

Electronic supplementary information:

## Effect of halide ratio and Cs<sup>+</sup> addition on the photochemical stability of lead halide perovskites

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### Sample preparation

FTO substrates were cleaned in an ultrasound bath in three 30 minutes steps with RBS<sup>TM</sup> 50 detergent, ethanol, and finally acetone. The substrates were subsequently treated in a UV-ozone cleaner for 10 minutes. An electron transport layer of TiO<sub>2</sub> was deposited on the cleaned FTO substrates using spray pyrolysis. The spray solution consisted of ethanol, acetyl acetone and titanium diisopropoxide (30% in isopropanol) in the proportions of 90:4:6 by volume. Air at a base pressure of 1 bar was used as a carrier gas. The FTO substrates were heated to 450 °C on a hotplate and kept at that temperature for 15 minutes prior to the spraying. After an additional 30 minutes at 450 °C, the sprayed glass substrates were slowly cooled to room temperature. 10 ml of spray solution was used to cover 200 cm<sup>2</sup> of substrates. This procedure gives a compact layer of anatase with a thickness of around 20-30 nm.

On top of the compact TiO<sub>2</sub>-layer, a mesoporous layer of TiO<sub>2</sub> nanoparticles was deposited by spin-coating. TiO<sub>2</sub> paste (30 NR-D) was bought from Great Cell Solar and was dissolved in ethanol at a concentration of 150 mg/ml. On each substrate (1.4·2.4 cm), 50 µl of the TiO<sub>2</sub> solution was applied and spin-coated at 4000 rpm with an acceleration of 2000 rpm/s for 10 s. A piece of scotch tape was used on one side of the substrates to prevent the mesoporous TiO<sub>2</sub> to form where the front contacts were to be deposited for complete solar cells. The substrates with mesoporous TiO<sub>2</sub> were sintered at 450 °C in air on a hot plate for 30 minutes and then slowly cooled to ambient temperature.

Prior to perovskite deposition, the substrates with mesoporous TiO<sub>2</sub> underwent a lithium treatment which has been found to be beneficial for the device performance [1]. On the substrates, 100 µl of a 35 mM lithium bistrifluoromethanesulfonimide (Li-TFSI) in acetonitrile was applied and spun at 3000 rpm for 10 s. The substrates were thermally annealed in air at 450 °C for 30 minutes and then slowly cooled to 150 °C. After annealing, they were transferred directly into a glovebox for perovskite deposition.

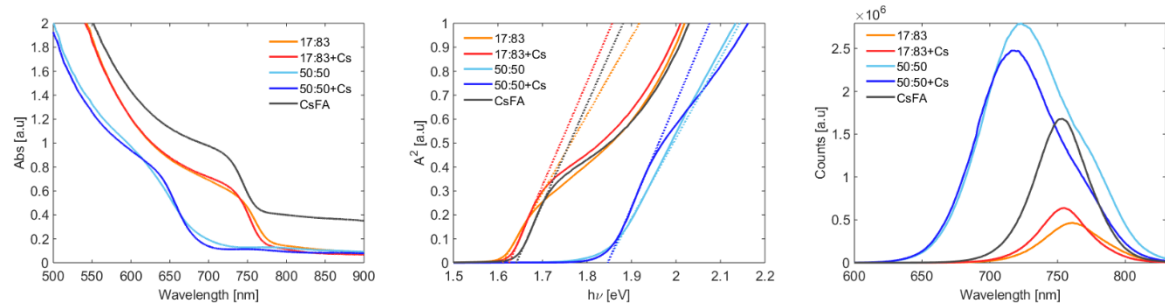
The perovskite precursor solutions were spin-coated in a nitrogen-filled glove box. For each sample, 40  $\mu\text{l}$  precursor solution was spread over the substrate and then spin-coated using a two-step program. The first step was a spreading step using a rotation speed of 1000 rpm with an acceleration of 200 rpm/s for 10 s. That step was immediately (without pause) followed by the second step where the films were spun at 6000 rpm for 20 s using an acceleration of 2000 rpm/s. During the second step, when approximately 5 seconds of the program remained, 100  $\mu\text{l}$  of anhydrous chlorobenzene were applied on the spinning film with a hand held automatic pipette. This last step, known as the anti-solvent method, has a large impact on film morphology and results in significantly better device performances [2]–[4]. Directly after spin-coating, the films were placed on a hotplate at 100 °C where they were annealed for 30-70 min.

After annealing, the samples were cooled to ambient temperature. For solar cells, a solution of the solid state hole-conductor ,2'7,7'-tetrakis-(*N,N*-di-*p*-methoxyphenyl-amine)-9,9'-spirobifluorene (spiro) was then spin-coated on top of the films. A 70 mM spiro in chlorobenzene was used to prepare the hole conductor layer. To improve the performance of spiro, three different additives were added [5], [6]: 4-*tert*-butylpyridine, 1.8 M Li-TFSI in acetonitrile, and 0.25 M Co[t-BuPyPz]<sub>3</sub>[TFSI]<sub>3</sub>, also known as FK209, in acetonitrile. The Spiro:FK209:Li-TFSI:TBP molar ratio was 1:0.05:0.5:3.3. The spiro solution was prepared and deposited on the same day as the perovskite films were deposited.

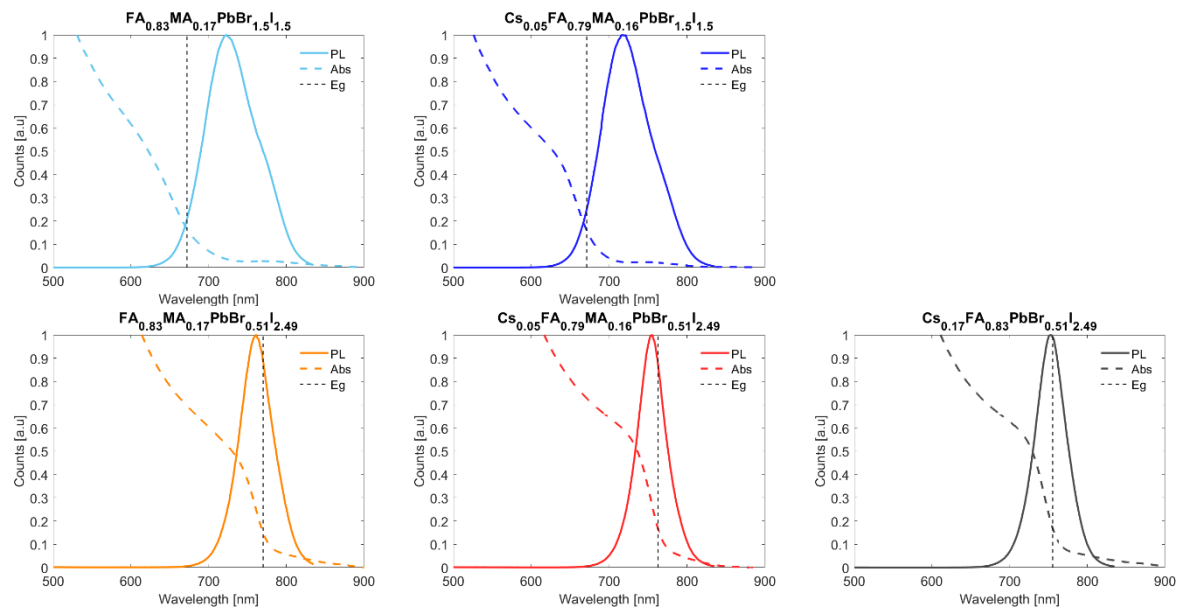
The spiro film was prepared by spin-coating at 4000 rpm for 20 s. 50  $\mu\text{l}$  of the solution were deposited on the spinning film using a hand held automatic pipet a few seconds into the spinning program. The samples were stored in a desiccator with silica gel.

Before the back contact was deposited, the perovskite/spiro layer was removed from one end of the samples using a razorblade, acetonitrile, and a cotton bud. An 80 nm thick gold film was deposited by vapour deposition at a pressure of around  $2 \cdot 10^{-5}$  Torr as a back contact.

## UV-vis and PL

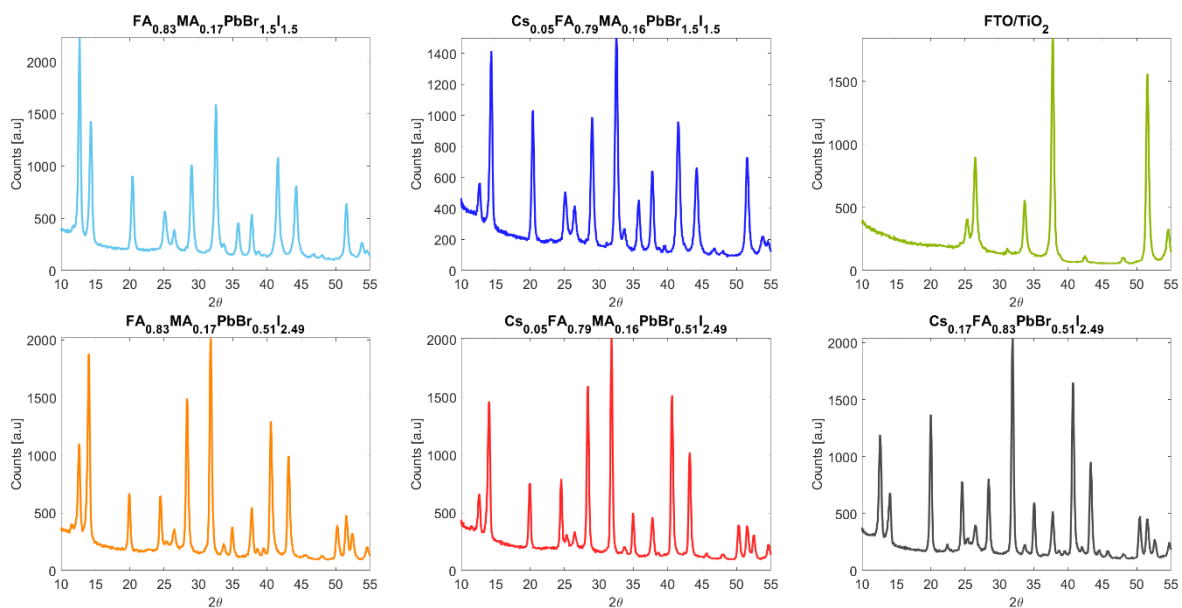


**Figure S1:** (a) Absorption spectra. Raw data. The higher background of the CsFA samples is due to more reflections/scattering, which is likely correlated to an increased surface roughness. (b) Graphical representation of how the band gaps were extracted. (c) Steady state fluorescence spectra. Not normalised.



**Figure S2:** Comparison of absorption data, steady state fluorescence and the extracted band gap for the investigated compositions.

## XRD



**Figure S3:** XRD data for the different compositions investigated. Measurements were performed on perovskite films deposited on FTO/TiO<sub>2</sub>.

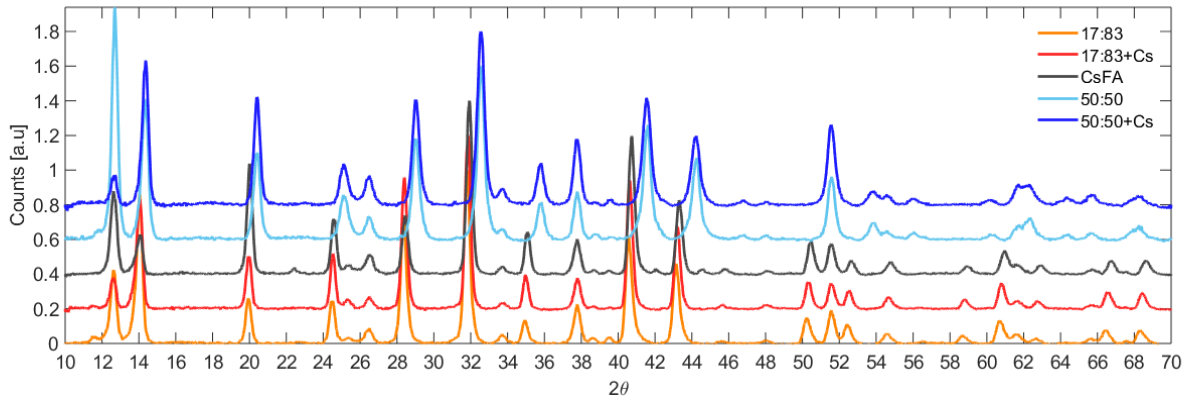


Figure S4: Comparison of the XRD diffractograms in Figure S3.

### SEM

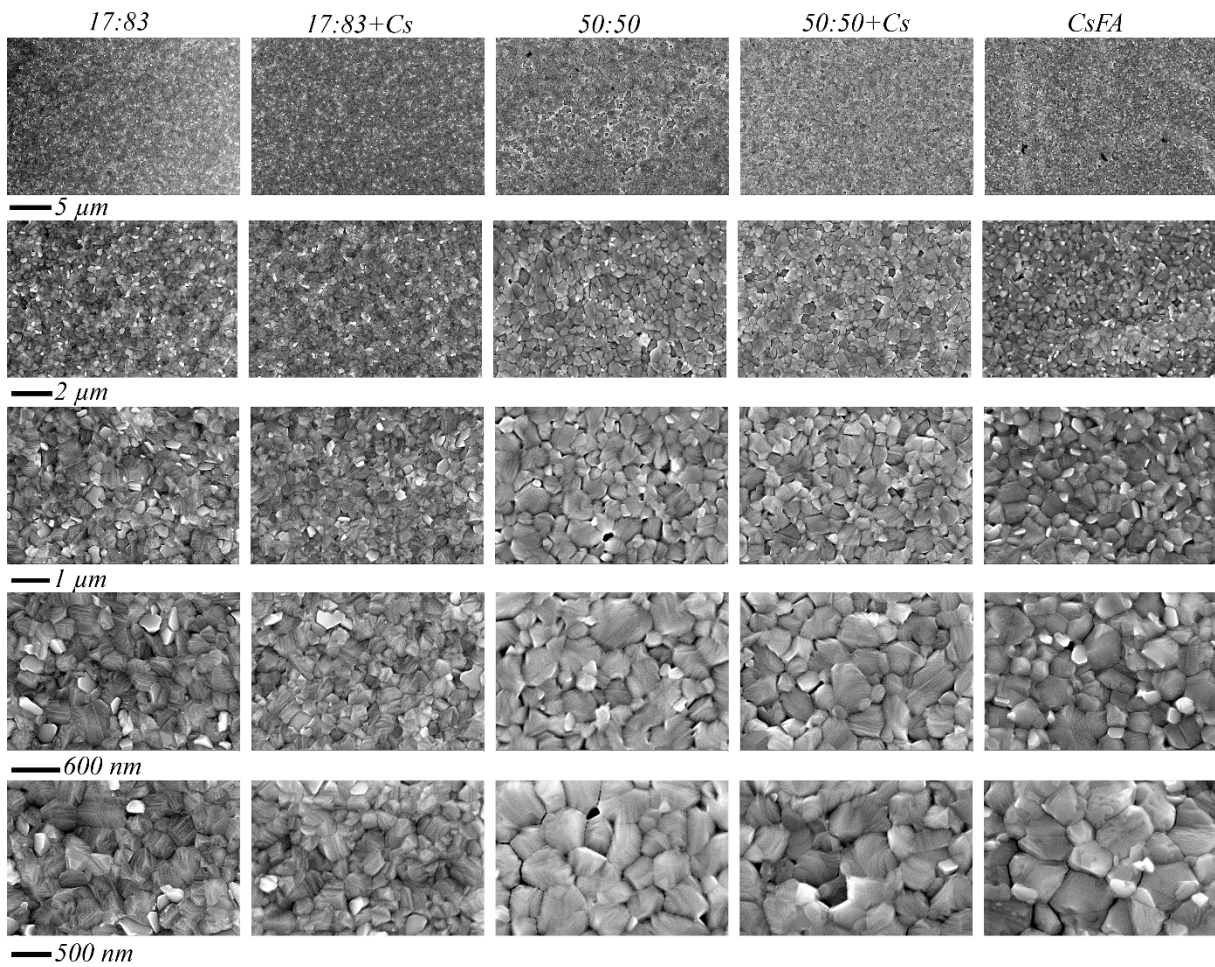


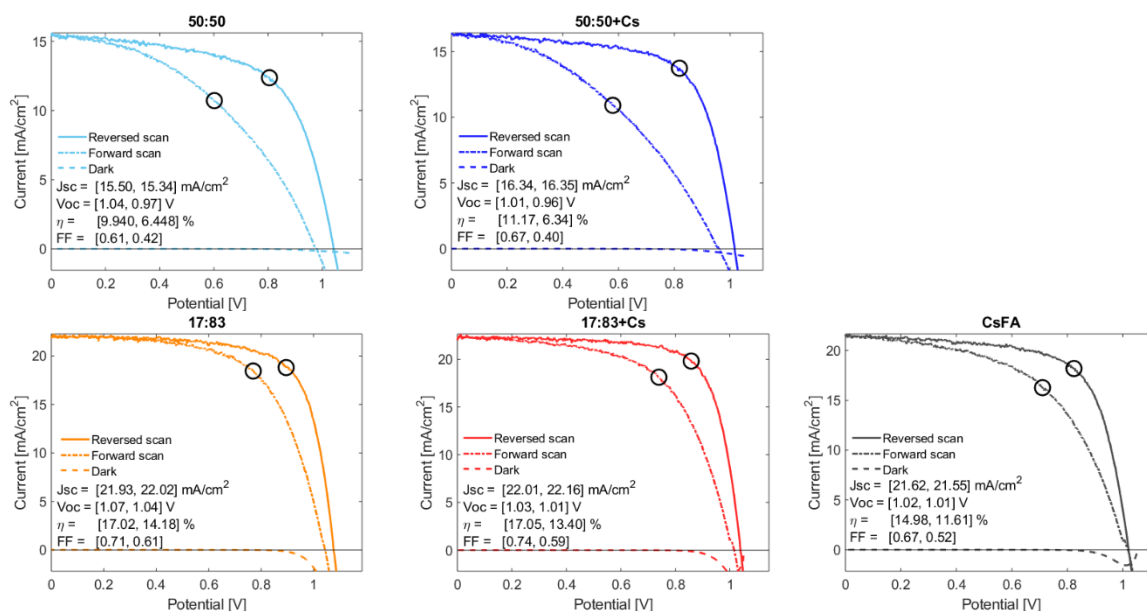
Figure S5: Top view SEM images at different magnifications of the five different compositions explored.

## Device characterisation

The IV-characteristics of the solar cells were measured using a home-built system. To simulate solar light, a Newport solar simulator (model 91160) with a xenon arc lamp, fed with 230 W input power and a AM 1.5 filter. The light intensity was calibrated with a silicon photodiode. The IV-curves were measured with a digital source meter (Keithley 2400). No equilibration time or light soaking was applied before the potential scan. The starting point for the measurements was chosen as  $V_{oc} + 0.05$  V. The potential was then scanned to short circuit and back again using a scan speed of 20 mV/s. Thereafter, the dark current was recorded using the same scan speed. The solar cells were masked with a metal mask in order to limit the active cell area to  $0.126 \text{ cm}^2$ .

**Table S1:** Summary of device data for the solar cells measured. Data is of the best sub cell (of two) on each substrate. One cell of each composition was made.

Composition	Name	$\eta_b$ [%]	$V_{ocb}$ [V]	$J_{scb}$ [ $\text{mA}/\text{cm}^2$ ]	$FF_b$ [%]	H	$\eta_f$ [%]	$V_{ocf}$ [V]	$J_{scf}$ [ $\text{mA}/\text{cm}^2$ ]	$FF_f$ [%]
$\text{FA}_{0.83}\text{MA}_{0.17}\text{PbBr}_{1.5}\text{I}_{1.5}$	50:50	9.9	1.04	15.5	0.62	0.21	6.4	0.98	15.3	0.43
$\text{Cs}_{0.05}\text{FA}_{0.79}\text{MA}_{0.16}\text{PbBr}_{1.5}\text{I}_{1.5}$	50:50+Cs	11.2	1.02	16.3	0.68	0.26	6.3	0.96	16.4	0.40
$\text{FA}_{0.83}\text{MA}_{0.17}\text{PbBr}_{0.51}\text{I}_{2.49}$	17:83	17.0	1.08	21.9	0.71	0.09	14.1	1.04	22.0	0.62
$\text{Cs}_{0.05}\text{FA}_{0.79}\text{MA}_{0.16}\text{PbBr}_{0.51}\text{I}_{2.49}$	17:83+Cs	17.1	1.04	22.0	0.74	0.12	13.4	1.02	22.2	0.60
$\text{Cs}_{0.17}\text{FA}_{0.83}\text{PbBr}_{0.51}\text{I}_{2.49}$	CsFA	15.0	1.02	21.6	0.68	0.11	11.6	1.02	21.6	0.53

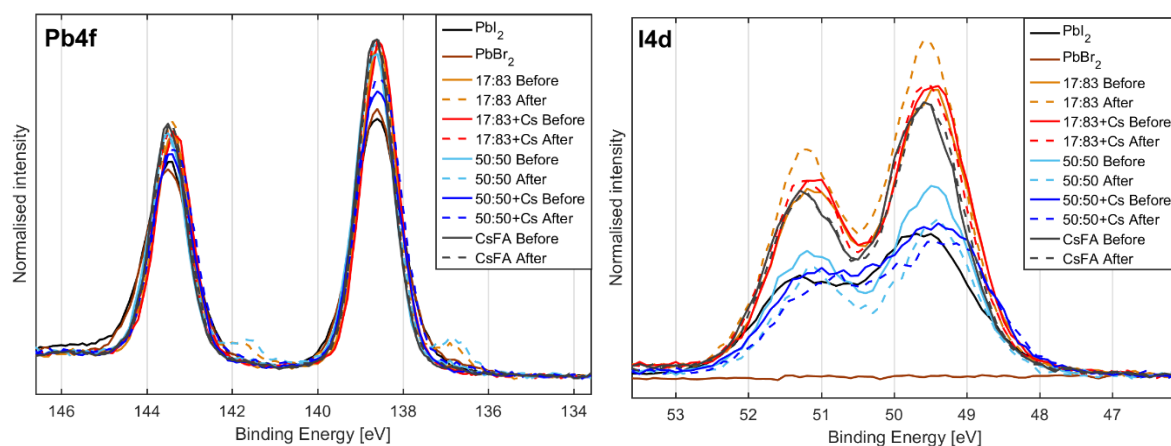


**Figure S6:** IV curves of solar cells made from the five different perovskite compositions.

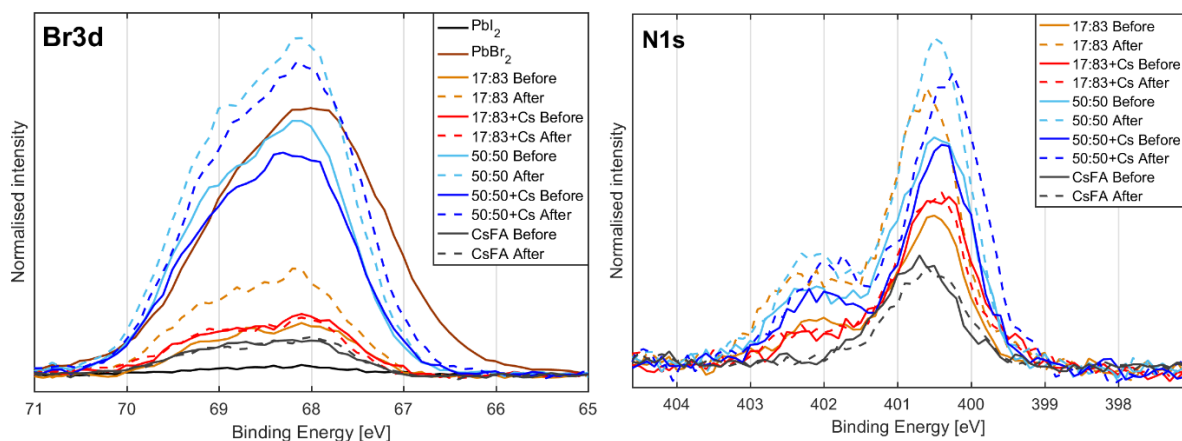
## Sample characterisation

**Table S2:** I/Pb(II) and Br/Pb(II) ratios of the perovskite samples at 120 eV, 139 eV, 147 eV and 540 eV before and after laser illumination for 30 minutes with 0.2 mW (after illumination is denoted with an L). The ratios are corrected against  $\text{PbI}_2$  and  $\text{PbBr}_2$  reference samples by setting the I/Pb(II) and Br/Pb(II) ratio of the reference samples to 2.

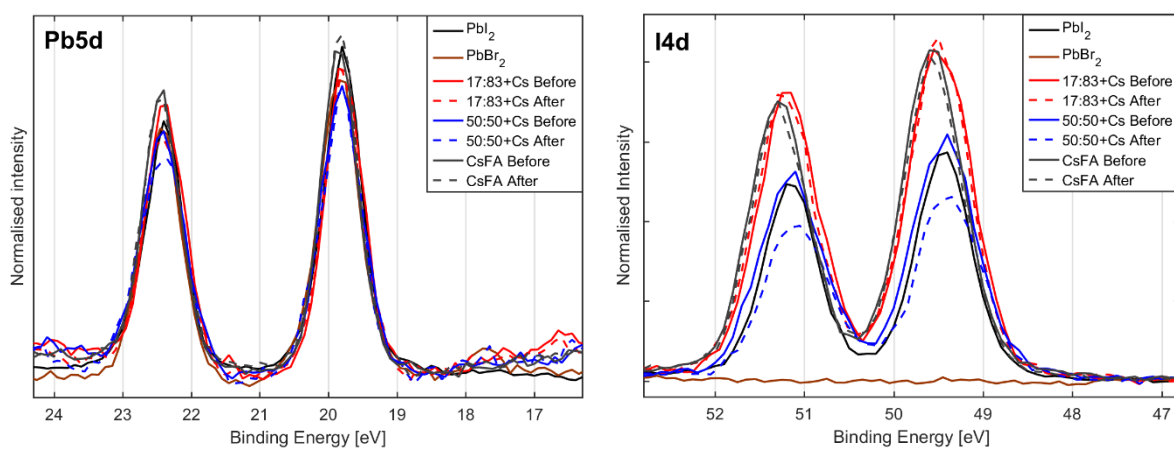
Reference	120 eV		139 eV		147 eV		540 eV	
	I/Pb(II)	Br/Pb(II)	I/Pb(II)	Br/Pb(II)	I/Pb(II)	Br/Pb(II)	I/Pb(II)	Br/Pb(II)
$\text{PbI}_2$	4.90	-	3.67	-	2.66	-	2.51	-
Correction	0.41	-	0.54	-	0.75	-	0.80	-
$\text{PbBr}_2$	-	0.41	-	0.46	-	0.49	-	3.09
Correction	-	4.88	-	4.35	-	4.08	-	0.65
Measured	I/Pb(II)	Br/Pb(II)	I/Pb(II)	Br/Pb(II)	I/Pb(II)	Br/Pb(II)	I/Pb(II)	Br/Pb(II)
<b>17:83</b>	7.23	0.09	5.80	0.11	-	-	4.20	0.56
<b>17:83 (L)</b>	9.10	0.17	7.01	0.22	-	-	4.72	1.01
<b>17:83+Cs</b>	7.97	0.08	5.50	0.10	4.39	0.12	4.24	0.60
<b>17:83+Cs (L)</b>	7.97	0.07	5.74	0.10	4.33	0.11	4.23	0.58
<b>50:50</b>	5.32	0.31	4.21	0.40	-	-	2.73	2.52
<b>50:50 (L)</b>	4.30	0.59	3.12	0.71	-	-	2.17	3.37
<b>50:50+Cs</b>	5.78	0.34	4.29	0.38	3.24	0.44	2.73	2.29
<b>50:50+Cs (L)</b>	5.78	0.47	3.59	0.63	2.52	0.72	2.31	3.08
<b>CsFA</b>	7.22	-	5.17	0.04	4.16	0.06	3.89	0.39
<b>CsFA (L)</b>	7.12	-	5.59	0.05	4.00	0.06	3.85	0.37
Corrected	I/Pb(II)	Br/Pb(II)	I/Pb(II)	Br/Pb(II)	I/Pb(II)	Br/Pb(II)	I/Pb(II)	Br/Pb(II)
$\text{PbI}_2$	2.00	-	2.00	-	2.00	-	2.00	-
$\text{PbBr}_2$	-	2.00	-	2.00	-	2.00	-	2.00
<b>17:83</b>	2.95	0.42	3.16	0.48	-	-	3.35	0.36
<b>17:83 (L)</b>	3.71	0.81	3.82	0.96	-	-	3.76	0.65
<b>17:83+Cs</b>	3.25	0.40	3.00	0.43	3.30	0.49	3.38	0.39
<b>17:83+Cs (L)</b>	3.25	0.35	3.13	0.43	3.26	0.45	3.37	0.38
<b>50:50</b>	2.17	1.51	2.29	1.74	-	-	2.18	1.63
<b>50:50 (L)</b>	1.76	2.87	1.70	3.09	-	-	1.73	2.18
<b>50:50+Cs</b>	2.36	1.65	2.34	1.65	2.44	1.80	2.17	1.48
<b>50:50+Cs (L)</b>	2.36	2.30	1.96	2.74	1.89	2.94	1.84	1.99
<b>CsFA</b>	2.95	-	2.82	0.17	3.13	0.24	3.10	0.25
<b>CsFA (L)</b>	2.91	-	3.04	0.21	3.01	0.24	3.07	0.24



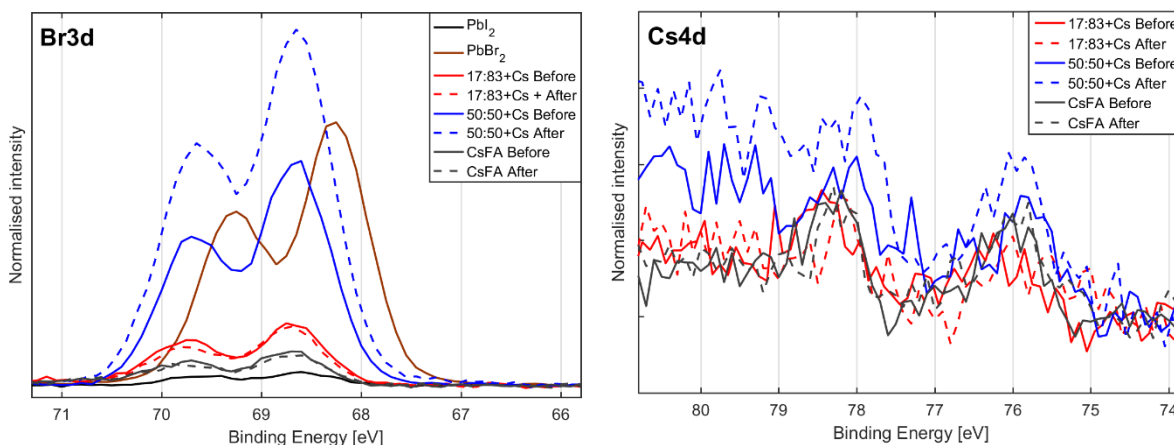
**Figure S7:**  $\text{Pb}4f$  and  $\text{I}4d$  spectra measured at 540 eV normalised to the  $\text{Pb(II)} 4f_{7/2}$  area and energy calibrated against  $\text{Pb(II)} 4f_{7/2}$  at 138.6 eV. The variation in peak height for  $\text{Pb}4f$  is due to variations in peak width and background shape.



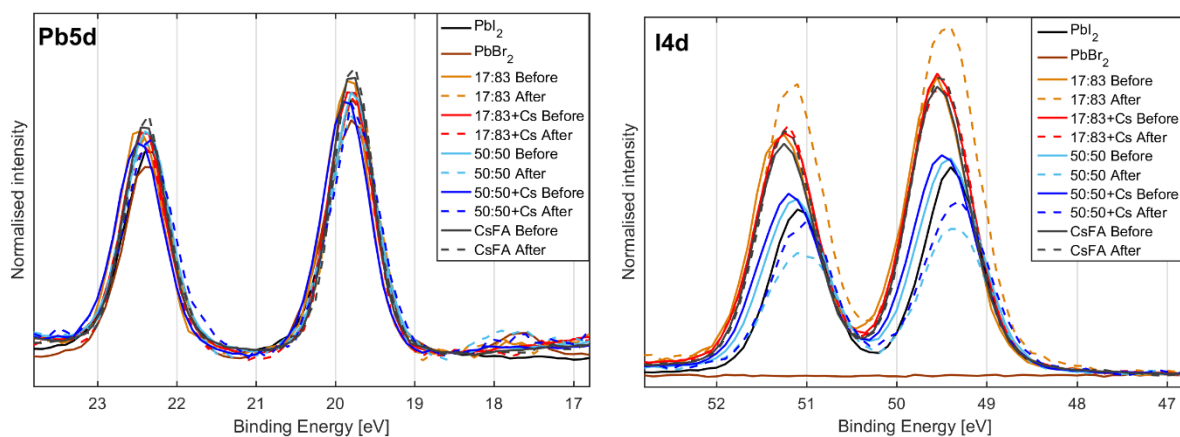
**Figure S8:** Br3d and N1s spectra measured at 540 eV normalised to the Pb(II) 4f area and energy calibrated against Pb(II) 4f<sub>7/2</sub> at 138.6 eV.



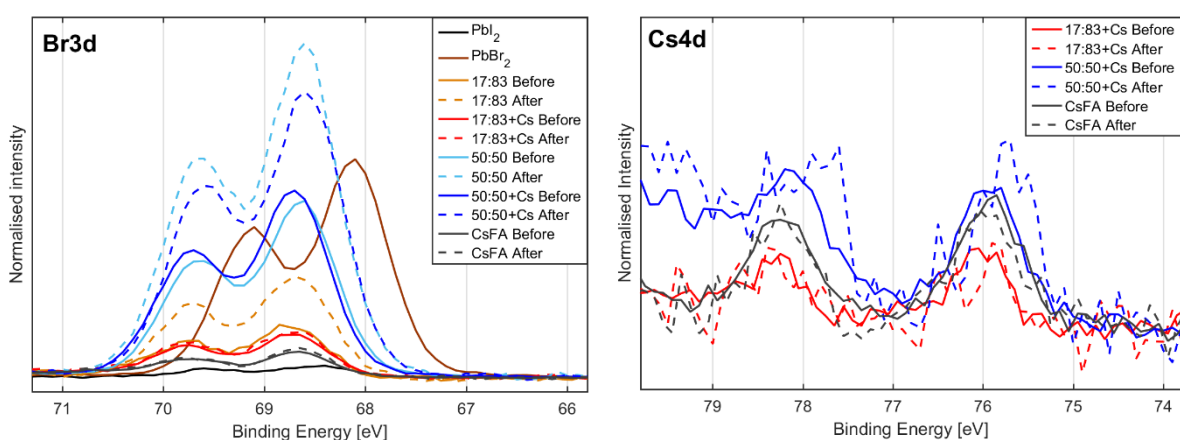
**Figure S9:** Pb5d and I4d spectra measured at 147 eV normalised to the Pb(II) 5d area and energy calibrated against Pb(II) 5d<sub>5/2</sub> at 19.8 eV. The variation in peak height for Pb5d is due to variations in peak width and background shape.



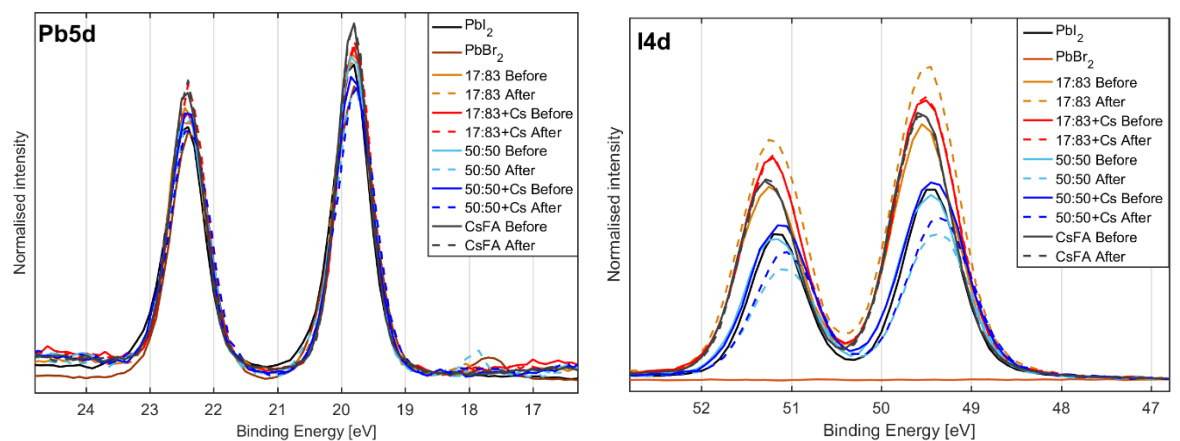
**Figure S7:** Br3d and Cs4d spectra measured at 147 eV normalised to the Pb(II) 5d area and energy calibrated against Pb(II) 5d<sub>5/2</sub> at 19.8 eV.



**Figure S11:** Pb5d and I4d spectra measured at 139 eV normalised to the Pb(II) 5d area and energy calibrated against Pb(II) 5d<sub>5/2</sub> at 19.8 eV. The variation in peak height for Pb5d is due to variations in peak width and background shape.

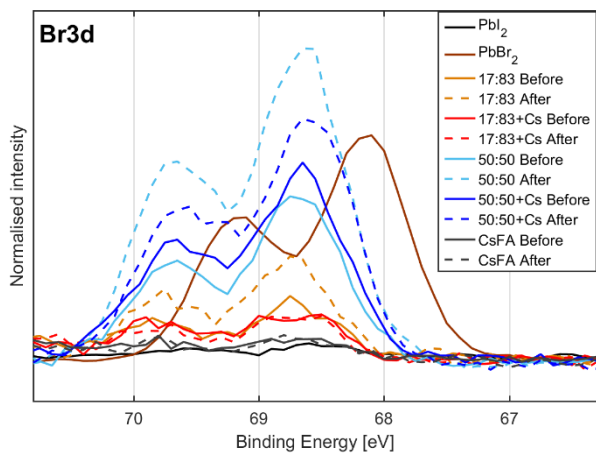


**Figure S12:** Br3d and Cs4d spectra measured at 139 eV normalised to the Pb(II) 5d area and energy calibrated against Pb(II) 5d<sub>5/2</sub> at 19.8 eV.



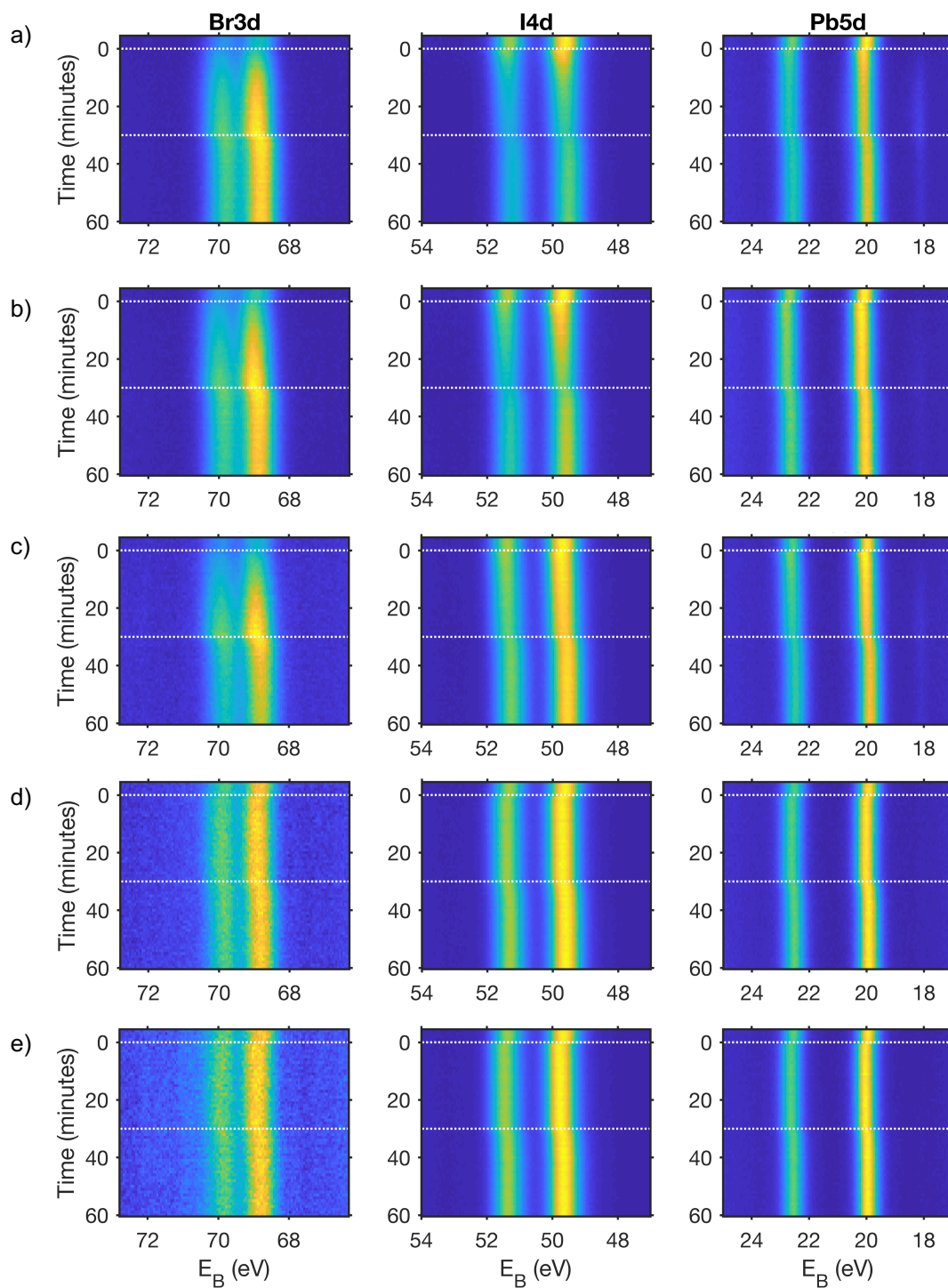
**Figure S13:** Pb5d and I4d spectra measured at 120 eV normalised to the Pb(II) 5d area and energy calibrated against Pb(II) 5d<sub>5/2</sub> at 19.8 eV. The variation in peak height for Pb5d is due to variations in peak width and background shape.



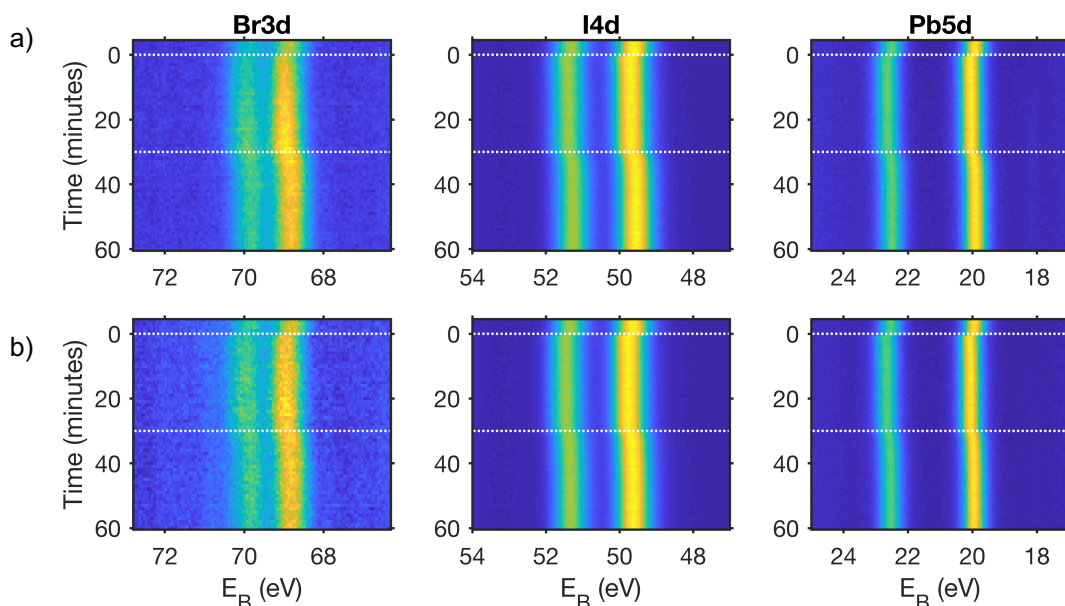


**Figure S14:** Br3d spectra measured at 120 eV normalised to the Pb(II) 5d area and energy calibrated against Pb(II) 5d<sub>5/2</sub> at 19.8 eV

## Spectral evolution before, during and after laser illumination



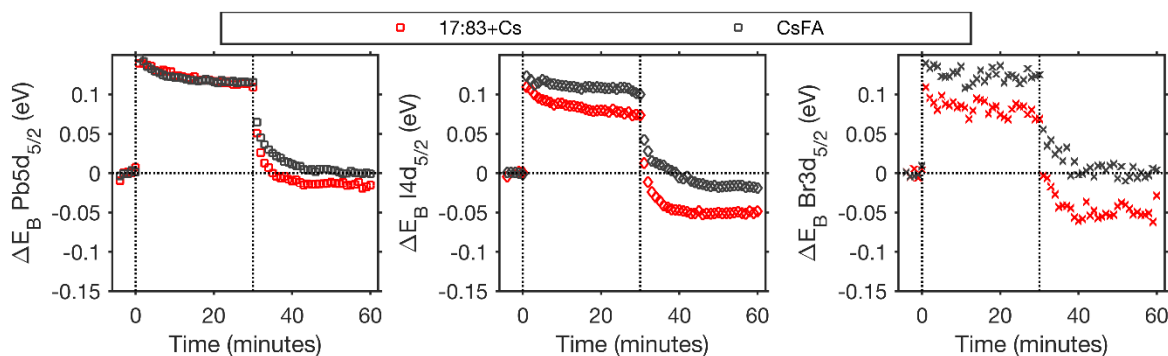
**Figure S15:** Time evolution of Br3d (left), I4d (middle) and Pb5d (right) spectra measured before, during and after laser illumination with 515 nm and 0.20 mW intensity. White horizontal lines indicate when the laser was switched on and off. The spectra are energy calibrated against the Fermi edge. a) 50:50, b) 50:50+Cs, c) 17:83, d) 17:83+Cs, e) CsFA



**Figure S16:** Time evolution of Br3d (left), I4d (middle) and Pb5d (right) spectra measured before, during and after laser illumination with 515 nm and 0.91 mW intensity. White horizontal lines indicate when the laser was switched on and off. The spectra are energy calibrated against the Fermi edge. a) 17:83+Cs, b) CsFA

## Peak shifts and sample characterisation

The changes in peak position of the Pb(+II), I(-I) and Br(-I) peaks during 0.91 mW laser illumination are presented in Figure S17. At this higher intensity we observe that the peak shift for CsFA returns to its original position but we do not observe this for 17:83+Cs, indicating that CsFA is more stable than 17:83+Cs.



**Figure S17:** The shift in peak position observed during illumination with 0.91 mW laser illumination relative to the original position. From left to right, Pb5d, I4d and Br3d.

## References

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